



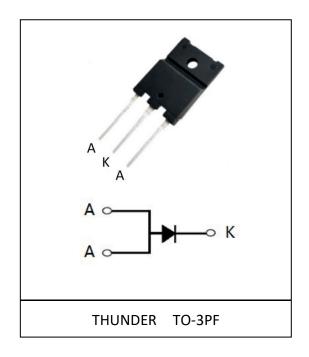
#### **Thunder High Power Products**

# FRED Ultrafast Soft Recovery Diode, 80A

#### **Features:**

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

Product Summary			
VR	600 V		
lf(AV)	80A		
trr	32ns		



### **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

## **Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	80	
Single pulse forward current	IFSM	Tc =25°C	800	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	160	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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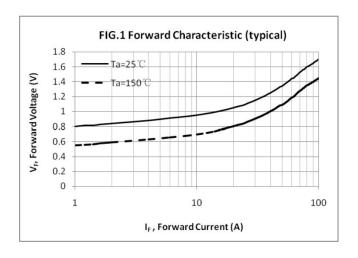
## Electrical characteristics (Ta=25°C unless otherwise specified)

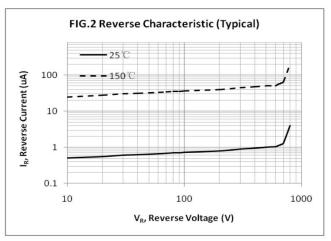
Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units	
Breakdown voltage Blocking voltage	VBR, V <sub>R</sub>	Ir=100µA	600				
Forward voltage (Per Diode)	VF	IF=80A		1.45	1.80	V	
		IF=80A, Tj =125°C		1.35	1.70		
Reverse leakage current(Per Diode)		VR= VRRM			50		
	l R	Tj=150°C, V <sub>R</sub> =600V			500	μ <b>Α</b>	
Reverse recovery time(Per Diode)		I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		55	80		
	trr	I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us		32	50	ns	

## Thermal characteristics

Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta$ JC	0.9	°C/W

## **Electrical performance (typical)**



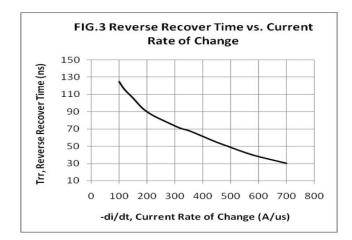


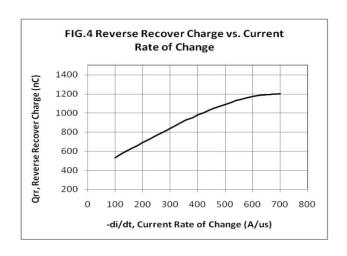
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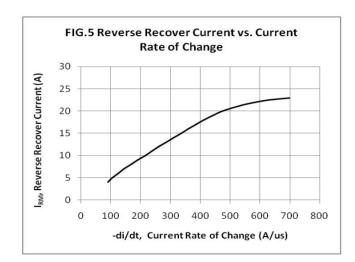


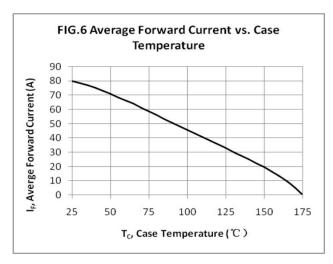


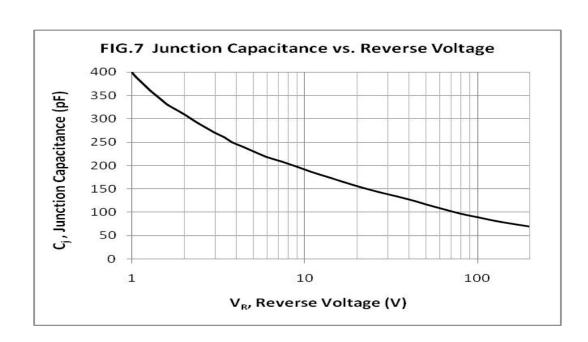












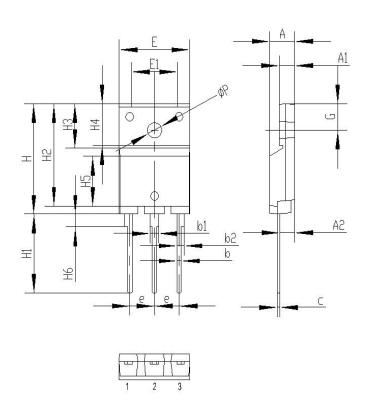
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#### **Package Information**

#### TO-3PF PACKAGE



Symbol	Dimensions(millimeters)	
Symbol	Min.	Max.
Α	5.30	5.70
A1	3.25	3.65
A2	3.15	3.55
b	0.80	1.20
b1	1.85	2.15
b2	1.45	1.75
С	0.40	0.80
е	5.25	5.65
Е	15.4	15.8
E1	10.0	10.4
Н	22.5	23.2
H1	16.0	17.0
H2	21.2	21.6
H3	9.10	9.50
H4	8.55	8.95
H5	10.20	10.60
H6	2.55	2.85
G	5.30	5.70
ΦР	3.00	3.40

#### **Notice**

Thunder Microelectronics Incorporated Limited reserves the right to make changes without further notice to any products or specifications herein. When use the product, be sure to obtain the latest specification.

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